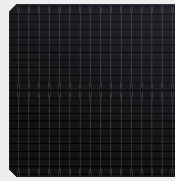
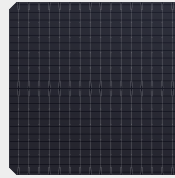


KEY FEATURES

-  High Photoelectric Conversion Efficiency
-  Higher Power Generation
-  Excellent Resistance to Hidden Cracks
-  Higher Efficiency in Power Generation



Front



Back

Size : 182.2mm*182.2mm±0.25mm

Thickness : 130±13μm

Solderability : ≥0.8N/mm

The results may vary depending to DS,welding methods and conditions.

Technical Data And Design

Power: -0.38%/K

Voltage: -0.30 %/K

Current: +0.048%/K

Front (-): 0.036±0.02mm busbars(silver)

Back (+): 0.036±0.02mm busbars(silver) black anti-reflecting coating(silicon nitride)

Front Electrical Performance Parameters

No.	Eff (%)	Voc	Isc	Vmpp	Impp	Pmpp
1	25.60	0.728	13.714	0.625	13.523	8.45
2	25.50	0.727	13.712	0.624	13.491	8.42
3	25.40	0.726	13.712	0.622	13.482	8.39
4	25.30	0.726	13.712	0.621	13.450	8.35
5	25.20	0.725	13.709	0.620	13.419	8.32
6	25.10	0.724	13.706	0.618	13.409	8.29
7	25.00	0.724	13.706	0.617	13.377	8.25
8	24.90	0.723	13.705	0.615	13.367	8.22
9	24.80	0.723	13.704	0.614	13.335	8.19
10	24.70	0.722	13.699	0.613	13.303	8.15
11	24.60	0.721	13.695	0.611	13.292	8.12
12	24.50	0.720	13.693	0.610	13.260	8.09

Iv Curve

